

### INCHANGE SEMICONDUCTOR

### **isc** Silicon NPN Power Transistor

## 2SC2307

#### DESCRIPTION

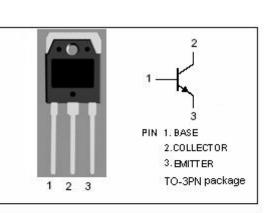
- Collector-Emitter Breakdown Voltage-V<sub>(BR)CEO</sub>= 400V(Min)
- High Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

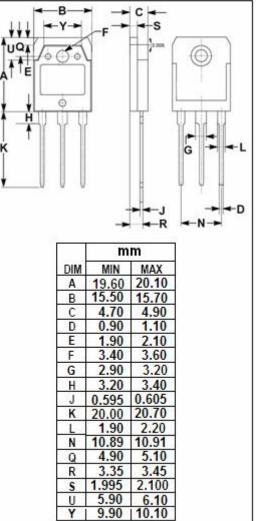
#### **APPLICATIONS**

• Designed for switching regulator and general purpose applications

#### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	500	v	
Vceo	Collector-Emitter Voltage	400	V	
V <sub>EBO</sub>	Emitter-Base Voltage	10	V	
lc	Collector Current-Continuous	12	A	
lв	Base Current-Continuous	4	A	
Pc	Collector Power Dissipation @ Tc=25℃	100	W	
TJ	Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	





1



### **isc Silicon NPN Power Transistor**

# 2SC2307

#### **ELECTRICAL CHARACTERISTICS**

#### 

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 25mA; I <sub>B</sub> = 0	400			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 7A; I <sub>B</sub> = 1.4A			0.5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	I <sub>C</sub> = 7A; I <sub>B</sub> = 1.4A			1.3	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 500V; I <sub>E</sub> = 0			100	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 10V; I <sub>C</sub> = 0			100	μA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 7A; V <sub>CE</sub> = 4V	10			
f⊤	Current-Gain—Bandwidth Product	I <sub>E</sub> = -1A; V <sub>CE</sub> = 12V		18		MHz

Switching Times

t <sub>on</sub>	Turn-on Time	I <sub>C</sub> = 7A ,R <sub>L</sub> = 14 Ω , I <sub>B1</sub> = -I <sub>B2</sub> = 1.4A, V <sub>CC</sub> = 100V		0.7	μ <b>S</b>
t <sub>stg</sub>	Storage Time			2.5	μs
tf	Fall Time			0.7	μs

Notice:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

2

isc website: www.iscsemi.com

isc & iscsemi is registered trademark